PCN Num	ber:	20210	210729000.2				PCN	Date:	August 3, 2021	
Title: Qualification of AIZU as an additional Wafer Fab Site option for select PiccoloB devices										
Customer	Contact:	PC	N Manage	er		Dept:		Qual	ity Services	
Proposed 1 st Ship Date:			b 3, 2022		Estimated Availabilit	Estimated Sample Da			provided at ble request.	
Change T	ype:								·	
Assem	nbly Site		Assemb	ly Pro	cess	[Assembly Materials			
Desigi					cification	[Mechanical Specification			
Test S			Packing/Shipping/Labeli			g [Test Process			
	Bump Site		Wafer Bump Material						ump Process	
🛛 Wafer	Fab Site		Wafer Fab Materials					Wafer F	ab Process	
			Part number change							
				PCN I	Details					
	on of Change					C ··· A 7=			<u> </u>	
									n facility as an	
additional	Wafer Fab sou	irce for t	ine selecte	ea dev	ices listed in	"Produo	ct A	rrected" s	section.	
	Currer	nt Sita				A d d i	lor	al Site		
			<u> </u>							
Curren		ess	Wafe		Additiona	r Pr	oce		Wafer	
Fab Sit		5	Diame 200m		Fab Site AIZU		F05		Diameter 200mm	
	J FU	5	20011	111	AIZU		105		20011111	
None	to product id						τγ (positive	/ negative):	
	•									
Current Chip Site	Chin	Sita Oria	gin (20L)	Chin	Site Countr	(Codo (211) Chin	Sita City	
		DM5								
DP1DM5					USA			Dallas		
Addition		Cito Onio	nin (201)	Chin	Cite Country	· Codo (211		Cite City	
Chip Site			gin (20L)	Chip	Site Countr	· ·	211	· ·	Site City	
	AIZU CU						I Aizuwakamatsu-sh			
MADE IN: 2DC: MSL '2 /24 MSL '2 /24 MSL 1 /22 OPT: ITEM: LBL: 5 Product A	Malaysia 29: 60C/1 YEAR SE 35C/UNLIM 03 6A (L)TO: 6ffected Grou	G4 G4 6/29/04 1750 p:			(1P) (Q) (31T) (4W) (P) (2P) R (20L) (22L)	TKY (11 EV: CSO: SHE ASO: MLA	395 (2 (2	(D) 033 9047ML 7523483 1L) CCO: 3L) ACO:	A 3SI2 USA TTYS	
KLITE32PA	GQR	TMS32	0F28031PN	Q	TMS320F2	8033PNQ	l	TMS3	20F28035PAGQ	
TMS320F2	8030PAGQ	TMS32	0F28032PA	GQ	TMS320F28034PAG			TMS3	20F28035PNQ	
TMS320F2	8030PNQ	TMS32	0F28032PN	Q	TMS320F2	8034PAG	QR	TMS3	20F28035PAGQ	
TMS320F2 TMS320F2		1	0F28032PN 0F28033PA	-	TMS320F2			TMS3	20F28035PAGQ	

Automotive Change Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Product Attributes

Attributes	Qual Device: TMS320F28035PNQ			
Automotive Grade Level	Grade 1			
Operating Temp Range Ta	-40 to +125 C			
Product Function	Microprocessor			
Die Attributes	-			
Wafer Fab Supplier	AIZU			
Other Attributes	Refer to CofDC			
Package Attributes	-			
Assembly Site	PHI			
Package Type	LQFP			
Package Designator	PN			
Ball/Lead Count	80			
Package Size (mils)	Refer to datasheet			

- QBS: Qual By Similarity
- Qual Device TMS320F28035PNQ is qualified at LEVEL3-260C.

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	e #	Test Spec	Min Lot Qty	SS/ Lot	Test Name / Condition	Duration	Qual Device: TMS320F28035PNO
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL3/260C	3/693/0
THB	8 A2	JEDEC JESD22- A101	3	77	Biased Temperature and Humidity, 85C/85%RH	1000 hours	3/231/0
AC	A3	JEDEC JESD22- A102	3	77	Autoclave 121C	96 hours	3/231/0
TC	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle, - 65/150C	500 cycles	3/231/0
			1	5	Post Temp cycle bond pull	Post 500 cycles	1/5/0
РТС	A5	JEDEC JESD22- A105	1	45	Power Temperature Cycle	1000 Cycles	N/A
HTSI	L A6	JEDEC JESD22- A103	1	45	High Temp Storage Bake 150C	1000 hours	3/231/0
	Test Group B – Accelerated Lifetime Simulation Tests						
HTO	L B1	JEDEC JESD22- A108	3	77	Life Test, 125C	1000 hours	3/231/0
ELFI	R B2	AEC Q100- 008	3	800	Early Life Failure Rate, 125C	48 hours	3/2400/0
EDR	B3	AEC Q100- 005	3	77	NVM Endurance, Data Retention, and Operational Life, 150C	1000 hours	3/231/0

Туре	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name / Condition	Duration	Qual Device: TMS320F28035PNQ
EDR	B3	AEC Q100- 005	3	77	Write/Erase Endurance prior to B1 and B3	1000 cycles	3/462/0
			roup C –	Packa	ige Assembly Integrity Tests		
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear (Cpk>1.67)	-	1/30/0
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull (Cpk>1.67)	-	1/30/0
SD	C3	JEDEC JESD22- B102	1	15	Surface Mount Solderability >95% Lead Coverage	-	1/15/0
PD	C4	JEDEC JESD22- B100 and B108	3	10	Physical Dimensions (Cpk>1.67)	-	3/30/0
			up D – D	ie Fab	rication Reliability Tests		
EM	D1	JESD61	-	-	Electromigration	EM	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	TDDB	Completed Per Process Technology Requirements
HCI	D3	JESD60 & 28	-	-	Hot Injection Carrier	HCI	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	NBTI	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	SM	Completed Per Process Technology Requirements
			up E – El	lectrica	al Verification Tests		
HBM	E2	AEC Q100- 002	1	3	ESD - HBM	2000V	1/3/0
CDM	E3	AEC Q100- 011	1	3	ESD - CDM	750V	1/3/0
LU	E4	AEC Q100- 004	1	6	Latch-up	125C	1/6/0
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	-	3/90/0

A1 (PC): Preconditioning:

Performed for THB, AC, TC & PTC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level: Grade 0 (or E): -40°C to +150°C Grade 1 (or Q): -40°C to +125°C Grade 2 (or T): -40° C to $+105^{\circ}$ C Grade 3 (or I) : -40° C to $+85^{\circ}$ C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold : HTOL, ED Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU Room : AC/uHAST

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